

## ULTRA FAST RECOVERY RECTIFIER DIODES

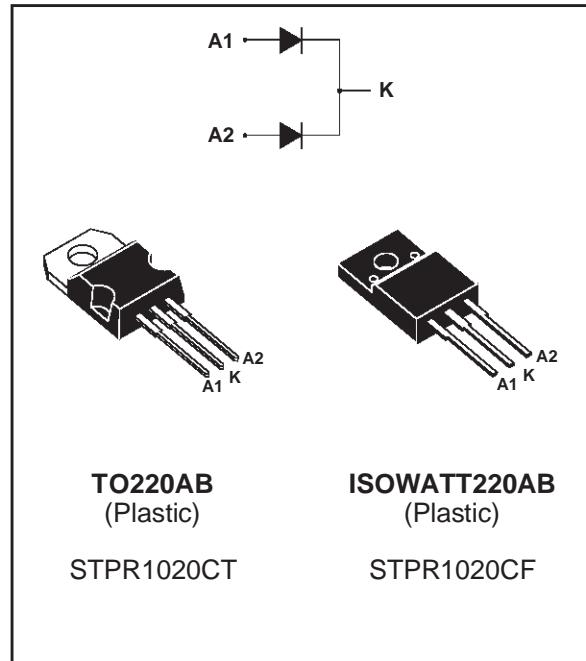
### FEATURES

- SUITED FOR SMPS
- LOW LOSSES
- LOW FORWARD AND REVERSE RECOVERY TIME
- HIGH SURGE CURRENT CAPABILITY
- HIGH AVALANCHE ENERGY CAPABILITY

### DESCRIPTION

Low cost dual center tap rectifier suited for switch-mode power supply and high frequency DC to DC converters.

Packaged in TO220AB and ISOWATT220AB, this device is intended for use in low voltage, high frequency inverters, free wheeling and polarity protection applications.



### ABSOLUTE MAXIMUM (limiting values)

Symbol	Parameter				Value	Unit
$V_{RRM}$	Repetitive peak reverse voltage				200	V
$I_{F(RMS)}$	RMS forward current			Per diode	10	A
$I_{F(AV)}$	Average forward current $\delta = 0.5$	TO220AB	Tc=125°C	Per diode	5	A
		ISOWATT220AB	Tc=115°C	Per device	10	
$I_{FSM}$	Surge non repetitive forward current		tp=10ms sinusoidal	Per diode	50	A
$T_{stg}$ $T_j$	Storage temperature range Maximum junction temperature				- 65 to + 150	°C
					- 65 to + 150	°C

## STPR1020CT/STPR1020CF

### THERMAL RESISTANCES

Symbol	Parameter			Value	Unit
$R_{th}(j-c)$	Junction to case	TO220AB	Per diode	4.0	$^{\circ}\text{C}/\text{W}$
		ISOWATT220AB	Per diode	6.0	

When the diodes 1 and 2 are used simultaneously :

$$\Delta T_j(\text{diode } 1) = P(\text{diode } 1) \times R_{th}(j-c) (\text{Per diode}) + P(\text{diode } 2) \times R_{th}(c)$$

### ELECTRICAL CHARACTERISTICS

#### STATIC CHARACTERISTICS

Symbol	Test Conditions		Min.	Typ.	Max.	Unit
$I_R$ *	$T_j = 25^{\circ}\text{C}$	$V_R = V_{RRM}$			50	$\mu\text{A}$
	$T_j = 100^{\circ}\text{C}$				0.6	mA
$V_F$ **	$T_j = 125^{\circ}\text{C}$	$I_F = 5 \text{ A}$			0.99	V
	$T_j = 125^{\circ}\text{C}$	$I_F = 10 \text{ A}$			1.20	
	$T_j = 25^{\circ}\text{C}$	$I_F = 10 \text{ A}$			1.25	

Pulse test :

\*  $t_p = 5 \text{ ms}$ ,  $\delta < 2 \%$

\*\*  $t_p = 380 \mu\text{s}$ ,  $\delta < 2 \%$

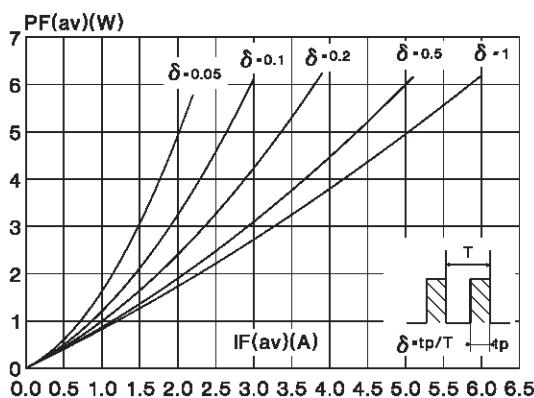
#### RECOVERY CHARACTERISTICS

Symbol	Test Conditions			Min.	Typ.	Max.	Unit
$tr$	$T_j = 25^{\circ}\text{C}$	$I_F = 0.5 \text{ A}$	$I_{rr} = 0.25 \text{ A}$			30	ns
$tfr$	$T_j = 25^{\circ}\text{C}$	$I_F = 1 \text{ A}$	$V_{FR} = 1.1 \times V_F$	$tr = 10 \text{ ns}$	20		ns
$V_{FP}$	$T_j = 25^{\circ}\text{C}$	$I_F = 1 \text{ A}$		$tr = 10 \text{ ns}$	3		V

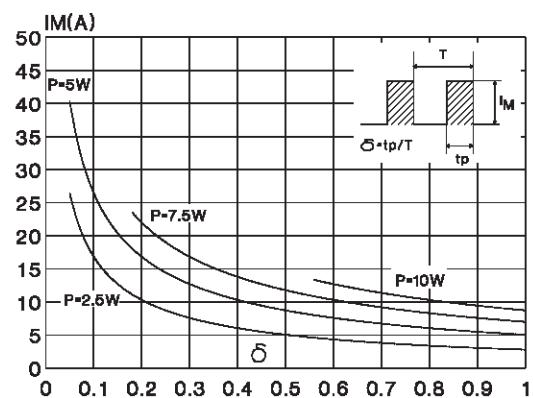
To evaluate the conduction losses use the following equation :

$$P = 0.78 \times I_{F(AV)} + 0.042 \times I_{F}^2(\text{RMS})$$

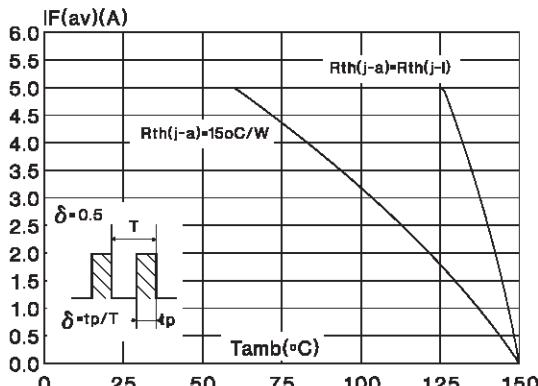
**Fig.1 :** Average forward power dissipation versus average forward current (Per diode).



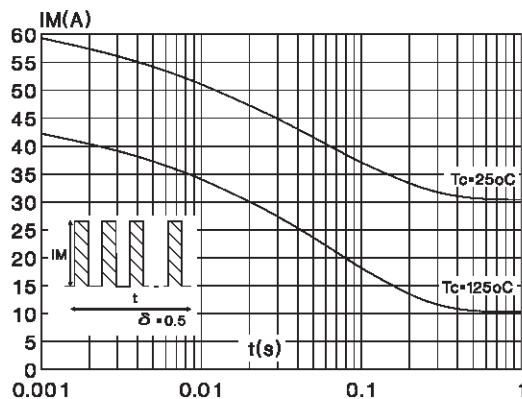
**Fig.2 :** Peak current versus form factor.(Per diode)



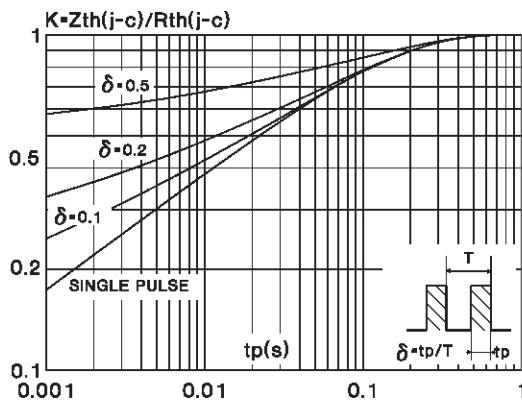
**Fig.3 :** Average current versus ambient temperature.  
(duty cycle : 0.5) (TO220AB)



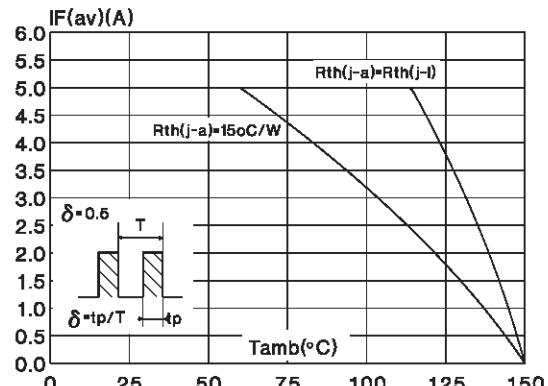
**Fig.5 :** Non repetitive surge peak forward current versus overload duration  
(Maximum values) (Per diode) (TO220AB).



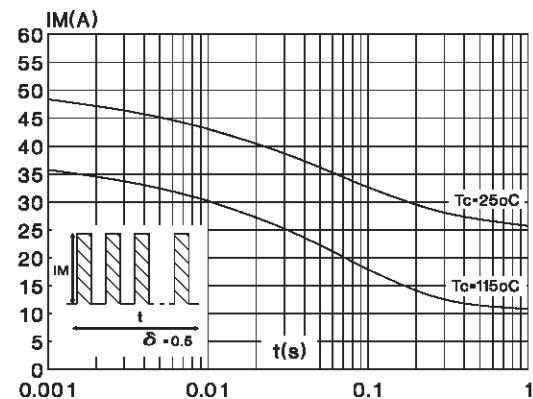
**Fig.7 :** Relative variation of thermal transient impedance junction to case versus pulse duration  
(Per diode) (TO220AB).



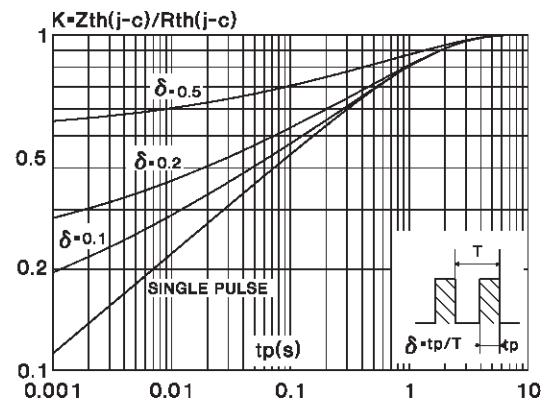
**Fig.4 :** Average current versus ambient temperature.  
(duty cycle : 0.5) (ISOWATT220AB)



**Fig.6 :** Non repetitive surge peak forward current versus overload duration  
(Maximum values) (Per diode) (ISOWATT220AB).

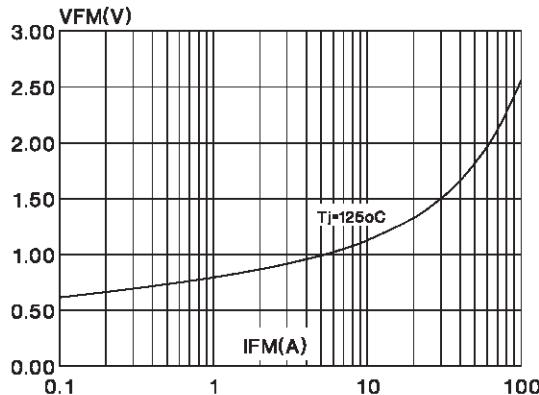


**Fig.8 :** Relative variation of thermal transient impedance junction to case versus pulse duration  
(Per diode) (ISOWATT220AB).

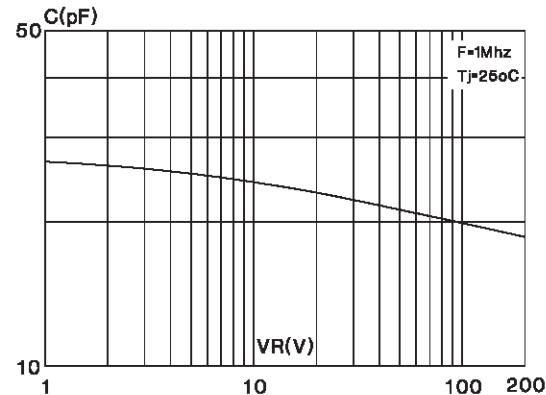


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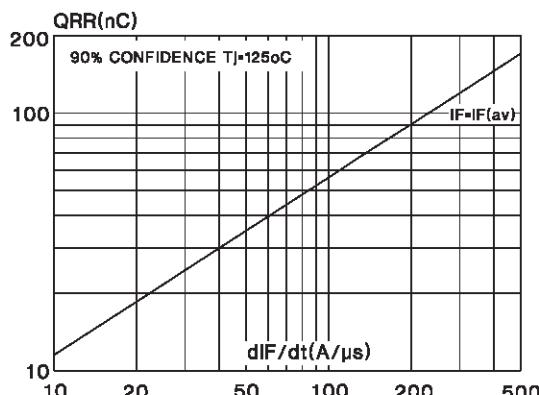
**Fig.9 :** Forward voltage drop versus forward current. (maximum values) (Per diode).



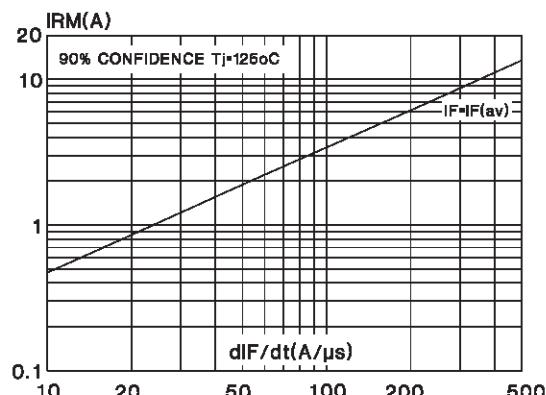
**Fig.10 :** Junction capacitance versus reverse voltage applied (Typical values) (Per diode).



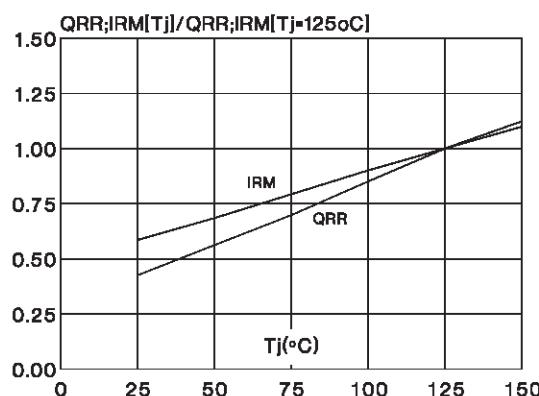
**Fig. 11:** Recovery charges versus  $dI_F/dt$  (Per diode).



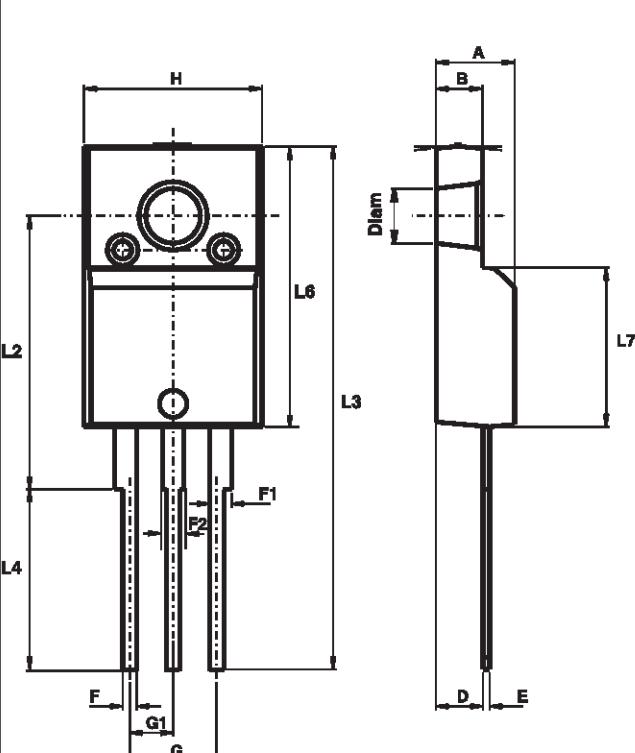
**Fig.12 :** Peak reverse current versus  $dI_F/dt$  (Per diode).



**Fig.13 :** Dynamic parameters versus junction temperature (Per diode).



**PACKAGE MECHANICAL DATA**  
ISOWATT220AB (JEDEC outline)



REF.	DIMENSIONS			
	Millimeters		Inches	
	Min.	Max.	Min.	Max.
A	4.40	4.60	0.173	0.181
B	2.50	2.70	0.098	0.106
D	2.50	2.75	0.098	0.108
E	0.40	0.70	0.016	0.028
F	0.75	1.00	0.030	0.039
F1	1.15	1.70	0.045	0.067
F2	1.15	1.70	0.045	0.067
G	4.95	5.20	0.195	0.205
G1	2.40	2.70	0.094	0.106
H	10.00	10.40	0.394	0.409
L2	16.00 Typ.		0.630 Typ.	
L3	28.60	30.60	1.125	1.205
L4	9.80	10.60	0.386	0.417
L6	15.90	16.40	0.626	0.646
L7	9.00	9.30	0.354	0.366
Diam	3.00	3.20	0.118	0.126

Cooling method : C  
Marking : Type number  
Weight : 2.08 g

Recommended torque value : 0.55m.N  
Maximum torque value : 0.70m.N

## STPR1020CT/STPR1020CF

### PACKAGE MECHANICAL DATA TO220AB (JEDEC outline)

REF.	DIMENSIONS			
	Millimeters		Inches	
	Min.	Max.	Min.	Max.
A	4.40	4.60	0.173	0.181
C	1.23	1.32	0.048	0.051
D	2.40	2.72	0.094	0.107
E	0.49	0.70	0.019	0.027
F	0.61	0.88	0.024	0.034
F1	1.14	1.70	0.044	0.066
F2	1.14	1.70	0.044	0.066
G	4.95	5.15	0.194	0.202
G1	2.40	2.70	0.094	0.106
H2	10	10.40	0.393	0.409
L2	16.4 typ.		0.645 typ.	
L4	13	14	0.511	0.551
L5	2.65	2.95	0.104	0.116
L6	15.25	15.75	0.600	0.620
L7	6.20	6.60	0.244	0.259
L9	3.50	3.93	0.137	0.154
M	2.6 typ.		0.102 typ.	
Diam.	3.75	3.85	0.147	0.151

Cooling method : C

Marking : Type number

Weight : 2.23 g

Recommended torque value : 0.8m.N

Maximum torque value : 1.0m.N

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